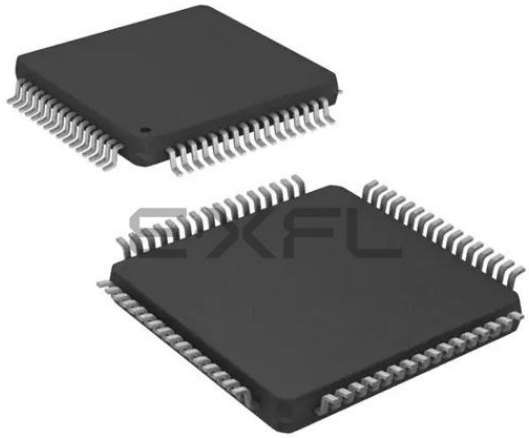

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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Not For New Designs
Core Processor	ARM® Cortex®-M3
Core Size	32-Bit Single-Core
Speed	50MHz
Connectivity	I²C, IrDA, SmartCard, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, LCD, POR, PWM, WDT
Number of I/O	51
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	8K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.8V
Data Converters	A/D 23x10/12b; D/A 1x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-TQFP
Supplier Device Package	64-TQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/sim3l136-c-gqr

Table 3.2. Power Consumption (Continued)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Power Mode 1[1,2,3,4]—Full speed with code executing from RAM, peripheral clocks ON	I_{BAT}	F_{AHB} = 49 MHz, F_{APB} = 24.5 MHz	—	13.4	16.6	mA
		F_{AHB} = 20 MHz, F_{APB} = 10 MHz	—	4.7	—	mA
		F_{AHB} = 2.5 MHz, F_{APB} = 1.25 MHz	—	810	—	µA
Power Mode 1[1,2,3,4]—Full speed with code executing from RAM, peripheral clocks OFF	I_{BAT}	F_{AHB} = 49 MHz, F_{APB} = 24.5 MHz	—	9.4	12.5	mA
		F_{AHB} = 20 MHz, F_{APB} = 10 MHz	—	3.3	—	mA
		F_{AHB} = 2.5 MHz, F_{APB} = 1.25 MHz	—	630	—	µA
Power Mode 1[1,2,3,4]—Full speed with code executing from RAM, LDOs powered by dc-dc at 1.9 V, peripheral clocks OFF	I_{BAT}	F_{AHB} = 49 MHz, F_{APB} = 24.5 MHz V_{BAT} = 3.3 V	—	7.05	—	mA
		F_{AHB} = 49 MHz, F_{APB} = 24.5 MHz V_{BAT} = 3.8 V	—	6.3	—	mA
		F_{AHB} = 20 MHz, F_{APB} = 10 MHz V_{BAT} = 3.3 V	—	2.75	—	mA
		F_{AHB} = 20 MHz, F_{APB} = 10 MHz V_{BAT} = 3.8 V	—	2.6	—	mA
Power Mode 2[1,2,3,4,5]—Core halted with peripheral clocks ON	I_{BAT}	F_{AHB} = 49 MHz, F_{APB} = 24.5 MHz	—	7.6	11.3	mA
		F_{AHB} = 20 MHz, F_{APB} = 10 MHz	—	2.75	—	mA
		F_{AHB} = 2.5 MHz, F_{APB} = 1.25 MHz	—	575	—	µA

Notes:

1. Currents are additive. For example, where I_{BAT} is specified and the mode is not mutually exclusive, enabling the functions increases supply current by the specified amount.
2. Includes all peripherals that cannot have clocks gated in the Clock Control module.
3. Includes LDO and PLL0OSC (>20 MHz) or LPOSC0 (≤20 MHz) supply current.
4. Internal Digital and Memory LDOs scaled to optimal output voltage.
5. Flash AHB clock turned off.
6. Running from internal LFO, Includes LFO supply current.
7. LCD0 current does not include switching currents for external load.
8. IDAC output current not included.
9. Does not include LC tank circuit.
10. Does not include digital drive current or pullup current for active port I/O. Unloaded I_{VIO} is included in all I_{BAT} PM8 production test measurements.

Table 3.5. On-Chip Regulators (Continued)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Memory LDO Output Setting[5]	V_{LDOMEM}	During Programming	1.8	—	1.9	V
		During Normal Operation	1.5	—	1.9	V
Digital LDO Output Setting	V_{LDODIG}	$F_{AHB} \leq 20$ MHz	1.0	—	1.9	V
		$F_{AHB} > 20$ MHz	1.2	—	1.9	V
Analog LDO Output Setting During Normal Operation[6]	V_{LDOANA}		1.8			V

Notes:

1. See reference manual for recommended inductors.
2. Recommended: X7R or X5R ceramic capacitors with low ESR. Example: Murata GRM21BR71C225K with ESR < 10 mΩ (@ frequency > 1 MHz).
3. Input voltage specification accounts for the internal LDO dropout voltage under the maximum load condition to ensure that the LDO output voltage will remain at a valid level as long as V_{LDOIN} is at or above the specified minimum.
4. The memory LDO output should always be set equal to or lower than the output of the analog LDO. When lowering both LDOs (for example to go into PM8 under low supply conditions), first adjust the memory LDO and then the analog LDO. When raising the output of both LDOs, adjust the analog LDO before adjusting the memory LDO.
5. Output range represents the programmable output range, and does not reflect the minimum voltage under all conditions. Dropout when the input supply is close to the output setting is normal, and accounted for.
6. Analog peripheral specifications assume a 1.8 V output on the analog LDO.

Table 3.9. SAR ADC

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Resolution	N_{bits}	12 Bit Mode		12		Bits
		10 Bit Mode		10		Bits
Supply Voltage Requirements (VBAT)	V_{ADC}	High Speed Mode	2.2	—	3.8	V
		Low Power Mode	1.8	—	3.8	V
Throughput Rate (High Speed Mode)	f_S	12 Bit Mode	—	—	250	ksps
		10 Bit Mode	—	—	1	Msps
Throughput Rate (Low Power Mode)	f_S	12 Bit Mode	—	—	62.5	ksps
		10 Bit Mode	—	—	250	ksps
Tracking Time	t_{TRK}	High Speed Mode	230	—	—	ns
		Low Power Mode	450	—	—	ns
SAR Clock Frequency	f_{SAR}	High Speed Mode	—	—	16.24	MHz
		Low Power Mode	—	—	4	MHz
Conversion Time	t_{CNV}	10-Bit Conversion, SAR Clock = 16 MHz, APB Clock = 40 MHz		762.5		ns
Sample/Hold Capacitor	C_{SAR}	Gain = 1	—	5	—	pF
		Gain = 0.5	—	2.5	—	pF
Input Pin Capacitance	C_{IN}	High Quality Inputs	—	18	—	pF
		Normal Inputs	—	20	—	pF
Input Mux Impedance	R_{MUX}	High Quality Inputs	—	300	—	Ω
		Normal Inputs	—	550	—	Ω
Voltage Reference Range	V_{REF}		1	—	V_{BAT}	V
Input Voltage Range*	V_{IN}	Gain = 1	0	—	V_{REF}	V
		Gain = 0.5	0	—	$2xV_{REF}$	V
Power Supply Rejection Ratio	$PSRR_{ADC}$		—	70	—	dB
DC Performance						
Integral Nonlinearity	INL	12 Bit Mode	—	±1	±1.9	LSB
		10 Bit Mode	—	±0.2	±0.5	LSB
Differential Nonlinearity (Guaranteed Monotonic)	DNL	12 Bit Mode	–1	±0.7	1.8	LSB
		10 Bit Mode	—	±0.2	±0.5	LSB
Offset Error (using VREFGND)	E_{OFF}	12 Bit Mode, VREF = 2.4 V	–2	0	2	LSB
		10 Bit Mode, VREF = 2.4 V	–1	0	1	LSB

Table 3.14. Comparator

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Response Time, CMPMD = 00 (Highest Speed)	t_{RESP0}	+100 mV Differential	—	100	—	ns
		–100 mV Differential	—	150	—	ns
Response Time, CMPMD = 11 (Lowest Power)	t_{RESP3}	+100 mV Differential	—	1.4	—	µs
		–100 mV Differential	—	3.5	—	µs
Positive Hysteresis Mode 0 (CPMD = 00)	HYS_{CP+}	CMPHYP = 00	—	0.37	—	mV
		CMPHYP = 01	—	7.9	—	mV
		CMPHYP = 10	—	16.7	—	mV
		CMPHYP = 11	—	32.8	—	mV
Negative Hysteresis Mode 0 (CPMD = 00)	HYS_{CP-}	CMPHYN = 00	—	0.37	—	mV
		CMPHYN = 01	—	–7.9	—	mV
		CMPHYN = 10	—	–16.1	—	mV
		CMPHYN = 11	—	–32.7	—	mV
Positive Hysteresis Mode 1 (CPMD = 01)	HYS_{CP+}	CMPHYP = 00	—	0.47	—	mV
		CMPHYP = 01	—	5.85	—	mV
		CMPHYP = 10	—	12	—	mV
		CMPHYP = 11	—	24.4	—	mV
Negative Hysteresis Mode 1 (CPMD = 01)	HYS_{CP-}	CMPHYN = 00	—	0.47	—	mV
		CMPHYN = 01	—	–6.0	—	mV
		CMPHYN = 10	—	–12.1	—	mV
		CMPHYN = 11	—	–24.6	—	mV
Positive Hysteresis Mode 2 (CPMD = 10)	HYS_{CP+}	CMPHYP = 00	—	0.66	—	mV
		CMPHYP = 01	—	4.55	—	mV
		CMPHYP = 10	—	9.3	—	mV
		CMPHYP = 11	—	19	—	mV
Negative Hysteresis Mode 2 (CPMD = 10)	HYS_{CP-}	CMPHYN = 00	—	0.6	—	mV
		CMPHYN = 01	—	–4.5	—	mV
		CMPHYN = 10	—	–9.5	—	mV
		CMPHYN = 11	—	–19	—	mV

3.3. Absolute Maximum Ratings

Stresses above those listed under Table 3.18 may cause permanent damage to the device. This is a stress rating only and functional operation of the devices at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

Table 3.18. Absolute Maximum Ratings

Parameter	Symbol	Test Condition	Min	Max	Unit
Ambient Temperature Under Bias	T_{BIAS}		–55	125	°C
Storage Temperature	T_{STG}		–65	150	°C
Voltage on VBAT/VBATDC	V_{BAT}		V_{SS}–0.3	4.2	V
Voltage on VDC	V_{DC}		V_{SSDC}–0.3	4.2	V
Voltage on VDRV	V_{DRV}		V_{SS}–0.3	4.2	V
Voltage on VIO	V_{IO}		V_{SS}–0.3	4.2	V
Voltage on VIORF	V_{IORF}		V_{SS}–0.3	4.2	V
Voltage on VLCD	V_{LCD}		V_{SS}–0.3	4.2	V
Voltage on I/O (PB0, PB1, PB3, PB4) or $\overline{\text{RESET}}$[1]	V_{IN}	$V_{IO} \geq 3.3$ V	V_{SS}–0.3	5.8	V
		$V_{IO} < 3.3$ V	V_{SS}–0.3	V_{IO}+2.5	V
Voltage on PB2 I/O Pins[1]	V_{IN}	$V_{IORF} \geq 3.3$ V	V_{SS}–0.3	5.8	V
		$V_{IORF} < 3.3$ V	V_{SS}–0.3	V_{IORF}+2.5	V
Total Current Sunk into Supply Pins	I_{SUPP}	VBAT/VBATDC, VIO, VIORF, VDRV, VDC, VLCD	—	400	mA
Total Current Sourced out of Ground Pins[2]	I_{VSS}	V_{SS}, V_{SSDC}	400	—	mA
Current Sourced or Sunk by any I/O Pin	I_{PIO}	All I/O and $\overline{\text{RESET}}$	–100	100	mA
Power Dissipation at T_A = 85 °C	P_D	TQFP-80 Packages	—	500	mW
		QFN-64 Packages	—	800	mW
		TQFP-64 Packages	—	650	mW
		QFN-40 Packages	—	650	mW

Notes:
1. Exceeding the minimum V_{IO} voltage may cause current to flow through adjacent device pins.
2. VSS and VSSDC provide separate return current paths for device supplies, but are not isolated. They must always be connected to the same potential on board.

4.1.5.6. Power Mode Summary

The power modes described above are summarized in Table 4.1. Table 3.2 and Table 3.3 provide more information on the power consumption and wake up times for each mode.

Table 4.1. SiM3L1xx Power Modes

Mode	Description	Notes
Normal	■ Core operating at full speed ■ Code executing from flash	■ Full device operation
Power Mode 1 (PM1)	■ Core operating at full speed ■ Code executing from RAM	■ Full device operation ■ Higher CPU bandwidth than PM0 (RAM can operate with zero wait states at any frequency)
Power Mode 2 (PM2)	■ Core halted ■ AHB, APB and all peripherals operational at full speed	■ Fast wakeup from any interrupt source
Power Mode 3 (PM3)	■ All clocks to core and peripherals stopped ■ Faster wake enabled by keeping LFOSC0 or RTC0TCLK active	■ Wake on any wake source or reset source defined in the PMU
Power Mode 4 (PM4)	■ Core operating at low speed ■ Code executing from flash	■ Same capabilities as PM0, operating at lower speed ■ Lower clock speed enables lower LDO output settings to save power
Power Mode 5 (PM5)	■ Core operating at low speed ■ Code executing from RAM	■ Same capabilities as PM1, operating at lower speed ■ Lower clock speed enables lower LDO output settings to save power
Power Mode 6 (PM6)	■ Core halted ■ AHB, APB and all peripherals operational at low speed	■ Same capabilities as PM2, operating at lower speed ■ Lower clock speed enables lower LDO output settings to save power ■ When running from LFOSC0, power is similar to PM3, but the device wakes much faster
Power Mode 8 (PM8)	■ Low power sleep ■ LDO regulators are disabled and all active circuitry operates directly from VBAT ■ The following functions are available: ACCTR0, RTC0, UART0 running from RTC0TCLK, LPTIMER0, port match, and the LCD controller ■ Register and RAM state retention	■ Lowest power consumption ■ Wake on any wake source or reset source defined in the PMU

4.5. Data Peripherals

4.5.1. 10-Channel DMA Controller

The DMA facilitates autonomous peripheral operation, allowing the core to finish tasks more quickly without spending time polling or waiting for peripherals to interrupt. This helps reduce the overall power consumption of the system, as the device can spend more time in low-power modes.

The DMA controller has the following features:

- Utilizes ARM PrimeCell uDMA architecture.
- Implements 10 channels.
- DMA crossbar supports DTM0, DTM1, DTM2, SARADC0, IDAC0, I2C0, SPI0, SPI1, USART0, AES0, ENCDEC0, EPCA0, external pin triggers, and timers.
- Supports primary, alternate, and scatter-gather data structures to implement various types of transfers.
- Access allowed to all AHB and APB memory space.

4.5.2. Data Transfer Managers (DTM0, DTM1, DTM2)

The Data Transfer Manager is a module that collects DMA request signals from various peripherals and generates a series of master DMA requests based on a state-driven configuration. This master request drives a set of DMA channels to perform functions such as assembling and transferring communication packets to external devices. This capability saves power by allowing the core to remain in a low power mode during complex transfer operations. A combination of simple and peripheral scatter-gather DMA configurations can be used to perform complex operations while reducing memory requirements.

The DTM acts as a side channel for the peripheral's DMA control signals. When active, it manages the DMA control signals for the peripherals. When the DTMn module is inactive, the peripherals communicate directly to the DMA module.

The DTMn module has the following features:

- State descriptions stored in RAM with up to 15 states supported per module.
- Supports up to 15 source peripherals and up to 15 destination peripherals per module, in addition to memory or peripherals that do not require a data request.
- Includes error detection and an optional transfer timeout.
- Includes notifications for state transitions.

4.5.3. 128/192/256-bit Hardware AES Encryption (AES0)

The basic AES block cipher is implemented in hardware. The integrated hardware support for Cipher Block Chaining (CBC) and Counter (CTR) algorithms results in identical performance, memory bandwidth, and memory footprint between the most basic Electronic Codebook (ECB) algorithm and these more complex algorithms. This hardware accelerator translates to more core bandwidth available for other functions or a power savings for low-power applications.

The AES module includes the following features:

- Operates on 4-word (16-byte) blocks.
- Supports key sizes of 128, 192, and 256 bits for both encryption and decryption.
- Generates the round key for decryption operations.
- All cipher operations can be performed without any firmware intervention for multiple 4-word blocks (up to 32 kB).
- Support for various chained and stream-ciphering configurations with XOR paths on both the input and output.
- Internal 4-word FIFOs to facilitate DMA operations.
- Integrated key storage.
- Hardware acceleration for Electronic Codebook (ECB), Cipher-Block Chaining (CBC), and Counter (CTR) algorithms utilizing integrated counterblock generation and previous-block caching.

4.5.4. 16/32-bit Enhanced CRC (ECRC0)

The ECRC module is designed to provide hardware calculations for flash memory verification and communications protocols. In addition to calculating a result from direct writes from firmware, the ECRC module can automatically snoop the APB bus and calculate a result from data written to or read from a particular peripheral. This allows for an automatic CRC result without directly feeding data through the ECRC module.

The supported 32-bit polynomial is 0x04C11DB7 (IEEE 802.3). The 16-bit polynomial is fully programmable.

The ECRC module includes the following features:

- Support for a programmable 16-bit polynomial and one fixed 32-bit polynomial.
- Byte-level bit reversal for the CRC input.
- Byte-order reorientation of words for the CRC input.
- Word or half-word bit reversal of the CRC result.
- Ability to configure and seed an operation in a single register write.
- Support for single-cycle parallel (unrolled) CRC computation for 32-, 16-, or 8-bit blocks.
- Capability to CRC 32 bits of data per peripheral bus (APB) clock.
- Automatic APB bus snooping.
- Support for DMA writes using firmware request mode.

4.5.5. Encoder / Decoder (ENCDEC0)

The encoder / decoder module supports Manchester and Three-out-of-Six encoding and decoding from either firmware or DMA operations.

This module has the following features:

- Supports Manchester and Three-out-of-Six encoding and decoding.
- Automatic flag clearing when writing the input or reading the output data registers.
- Writing to the input data register automatically initiates an encode or decode operation.
- Optional output in one’s complement format.
- Hardware error detection for invalid input data during decode operations, which helps reduce power consumption and packet turn-around time.
- Flexible byte swapping on the input or output data.

4.6. Counters/Timers

4.6.1. 32-bit Timer (TIMER0, TIMER1, TIMER2)

Each timer module is independent, and includes the following features:

- Operation as a single 32-bit or two independent 16-bit timers.
- Clocking options include the APB clock, the APB clock scaled using an 8-bit prescaler, the external oscillator, or falling edges on an external input pin (synchronized to the APB clock).
- Auto-reload functionality in both 32-bit and 16-bit modes.

TIMER0 and TIMER1 have the following features:

- Up/Down count capability, controlled by an external input pin.
- Rising and falling edge capture modes.
- Low or high pulse capture modes.
- Period and duty cycle capture mode.
- Square wave output mode, which is capable of toggling an external pin at a given rate with 50% duty cycle.
- 32- or 16-bit pulse-width modulation mode.

TIMER2 does not support the standard input/output features of TIMER0 and TIMER1. The TIMER2 EX signal is internally connected to the outputs of the PVTOSC0 oscillators. TIMER2 can use any of the counting modes that use EX as an input, including up/down mode, edge capture mode, and pulse capture mode. The TIMER2 CT signal is disconnected.

4.6.2. Enhanced Programmable Counter Array (EPCA0)

The Enhanced Programmable Counter Array (EPCA) module is a timer/counter system allowing for complex timing or waveform generation. Multiple modules run from the same main counter, allowing for synchronous output waveforms.

This module includes the following features:

- Three sets of channel pairs (six channels total) capable of generating complementary waveforms.
- Center- and edge-aligned waveform generation.
- Programmable dead times that ensure channel pairs are never active at the same time.
- Programmable clock divisor and multiple options for clock source selection.
- Waveform update scheduling.
- Option to function while the core is inactive.
- Multiple synchronization triggers.
- Pulse-Width Modulation (PWM) waveform generation.

5. Ordering Information

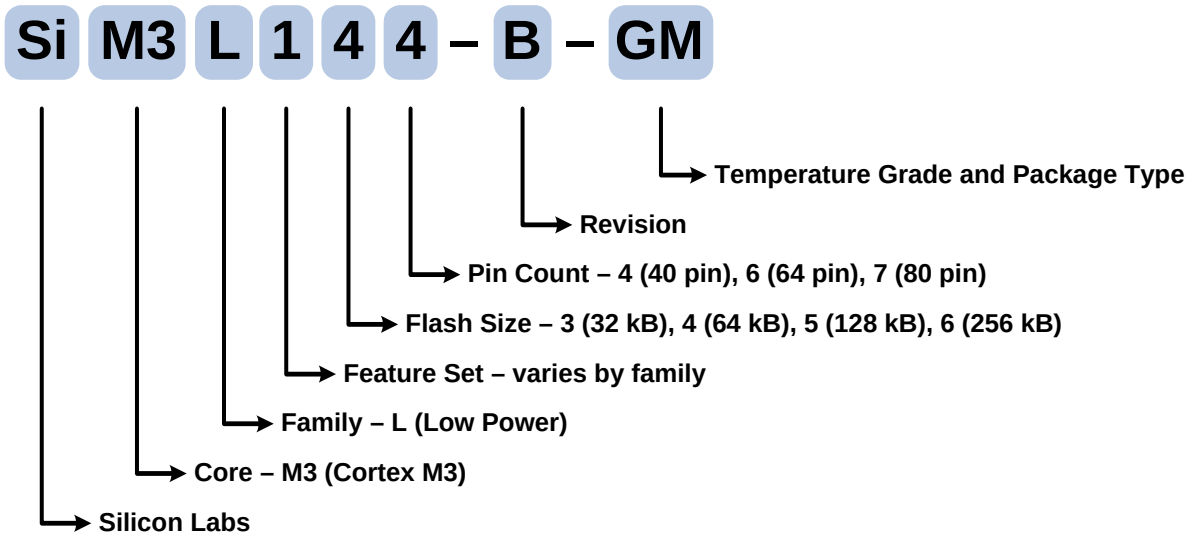

Figure 5.1. SiM3L1xx Part Numbering

All devices in the SiM3L1xx family have the following features:

- **Core:** ARM Cortex-M3 with maximum operating frequency of 50 MHz.
- **PLL.**
- **10-Channel DMA Controller.**
- **128/192/256-bit AES.**
- **16/32-bit CRC.**
- **Encoder/Decoder.**
- **DC-DC Buck Converter.**
- **Timers:** 3 x 32-bit (6 x 16-bit).
- **Real-Time Clock.**
- **Low-Power Timer.**
- **PCA:** 1 x 6 channels (Enhanced)
- **ADC:** 12-bit 250 ksps (10-bit 1 Msps) SAR.
- **DAC:** 10-bit IDAC.
- **Temperature Sensor.**
- **Internal VREF.**
- **Comparator:** 2 x low current.
- **Serial Buses:** 2 x USART, 2 x SPI, 1 x I2C

Additionally, all devices in the SiM3L1xx family include the low power mode advanced capture counter (ACCTR0), though the smaller packages (SiM3L1x4) only support some of the external inputs and outputs.

6. Pin Definitions

6.1. SiM3L1x7 Pin Definitions

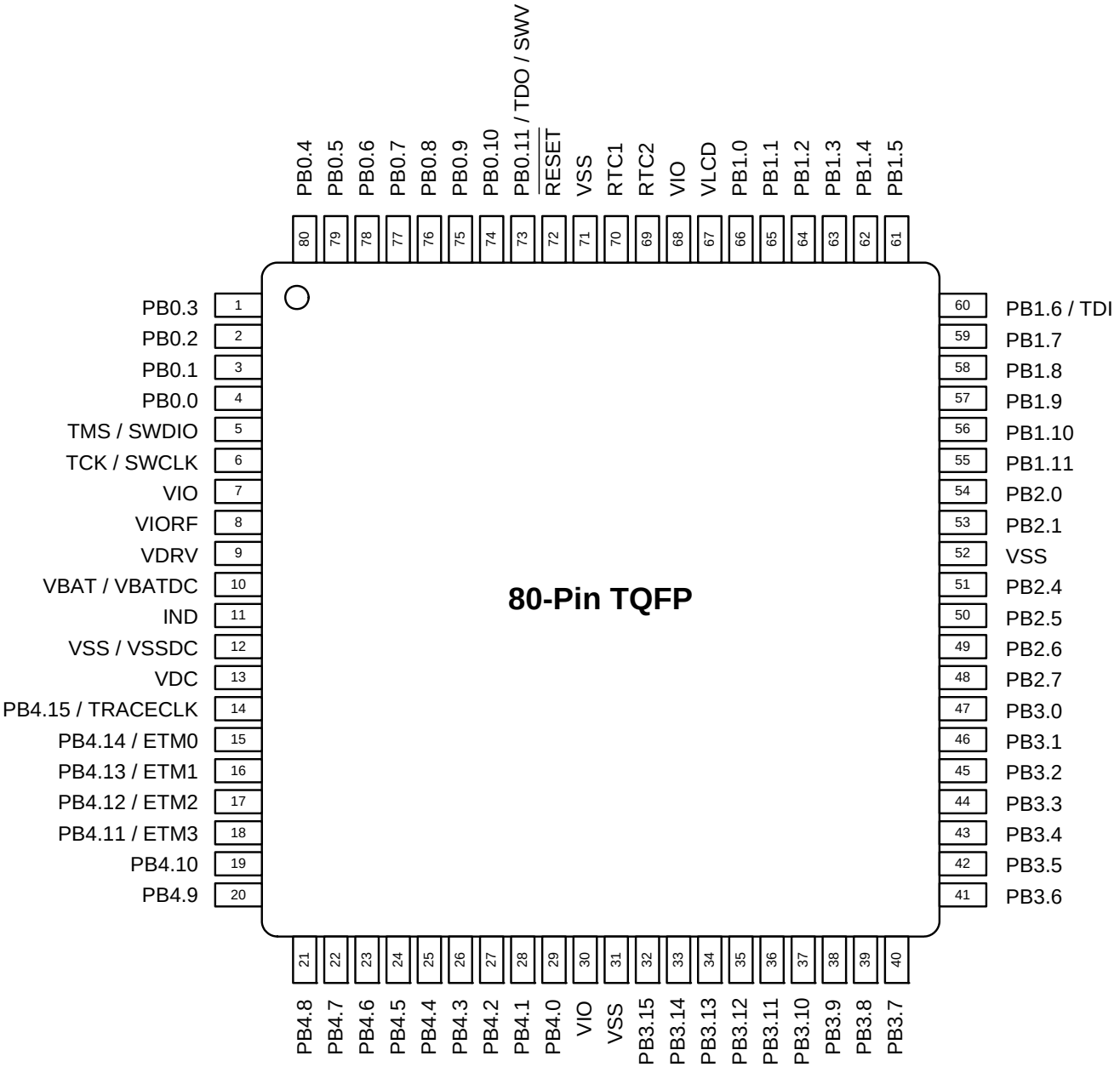

Figure 6.1. SiM3L1x7-GQ Pinout

Table 6.1. Pin Definitions and Alternate Functions for SiM3L1x7 (Continued)

Pin Name	Type	Pin Numbers (TQFP-80)	I/O Voltage Domain	Crossbar Capability	Port Match	LCD Interface	Output Toggle Logic	External Trigger Inputs / Digital Functions	Analog Functions
PB0.9	Standard I/O	75	VIO	✓	✓		✓	LPT0T1 INT0.9 WAKE.9 ACCTR0_LCPUL0	ADC0.1 CMP0N.1
PB0.10	Standard I/O	74	VIO	✓	✓		✓	LPT0T2 INT0.10 WAKE.10 ACCTR0_LCPUL1	ADC0.2 CMP1P.1
PB0.11/ TDO/SWV	Standard I/O / JTAG / Serial Wire Viewer	73	VIO	✓	✓		✓	LPT0T3 LPT0OUT1 INT0.11 WAKE.11	ADC0.3 CMP1N.1
PB1.0	Standard I/O	66	VIO	✓	✓	LCD0.39		LPT0T4 INT0.12 ACCTR0_LCBIAS0	CMP0P.2
PB1.1	Standard I/O	65	VIO	✓	✓	LCD0.38		LPT0T5 INT0.13 ACCTR0_LCBIAS1	CMP0N.2
PB1.2	Standard I/O	64	VIO	✓	✓	LCD0.37		LPT0T6 INT0.14 UART0_TX	CMP1P.2
PB1.3	Standard I/O	63	VIO	✓	✓	LCD0.36		LPT0T7 INT0.15 UART0_RX	CMP1N.2
PB1.4	Standard I/O	62	VIO	✓	✓	LCD0.35		ACCTR0_DBG0	ADC0.4
PB1.5	Standard I/O	61	VIO	✓	✓	LCD0.34		ACCTR0_DBG1	ADC0.5
PB1.6/TDI	Standard I/O / JTAG	60	VIO	✓	✓	LCD0.33			ADC0.6
PB1.7	Standard I/O	59	VIO	✓	✓	LCD0.32		RTC0TCLK_OUT	ADC0.7

Table 6.1. Pin Definitions and Alternate Functions for SiM3L1x7 (Continued)

Pin Name	Type	Pin Numbers (TQFP-80)	I/O Voltage Domain	Crossbar Capability	Port Match	LCD Interface	Output Toggle Logic	External Trigger Inputs / Digital Functions	Analog Functions
PB1.8	Standard I/O	58	VIO	✓	✓	LCD0.31			CMP0P.3
PB1.9	Standard I/O	57	VIO	✓	✓	LCD0.30			CMP0N.3
PB1.10	Standard I/O	56	VIO	✓	✓	LCD0.29			CMP1P.3
PB1.11	Standard I/O	55	VIO	✓	✓	LCD0.28			CMP1N.3
PB2.0	Standard I/O	54	VIORF	✓	✓			LPT0T8 INT1.0 WAKE.12 SPI1_CTS	ADC0.8 CMP0P.4
PB2.1	Standard I/O	53	VIORF	✓	✓			LPT0T9 INT1.1 WAKE.13 VIORFCLK	ADC0.9 CMP0N.4
PB2.4	Standard I/O	51	VIORF	✓	✓			LPT0T12 INT1.4 SPI1_SCLK	ADC0.10 CMP0P.5
PB2.5	Standard I/O	50	VIORF	✓	✓			LPT0T13 INT1.5 SPI1_MISO	ADC0.11 CMP0N.5
PB2.6	Standard I/O	49	VIORF	✓	✓			LPT0T14 INT1.6 SPI1_MOSI	ADC0.12 CMP1P.5
PB2.7	Standard I/O	48	VIORF	✓	✓			INT1.7 SPI1_NSS	ADC0.13 CMP1N.5
PB3.0	Standard I/O	47	VIO	✓	✓	LCD0.27		INT1.8	ADC0.14
PB3.1	Standard I/O	46	VIO	✓	✓	LCD0.26		INT1.9	ADC0.15
PB3.2	Standard I/O	45	VIO	✓	✓	LCD0.25		INT1.10	ADC0.16
PB3.3	Standard I/O	44	VIO	✓	✓	LCD0.24		INT1.11	ADC0.17

Table 6.3. Pin Definitions and Alternate Functions for SiM3L1x4

Pin Name	Type	Pin Numbers	I/O Voltage Domain	Crossbar Capability	Port Match	Output Toggle Logic	External Trigger Inputs / Digital Functions	Analog Functions
VSS	Ground	9 25						
VSSDC	Ground (DC-DC)	9						
VIO	Power (I/O)	5						
VIORF / VDRV	Power (RF I/O)	6						
VBAT / VBATDC		7						
VDC		10						
IND	DC-DC Inductor	8						
$\overline{\text{RESET}}$	Active-low Reset	35						
SWCLK	Serial Wire	4						
SWDIO	Serial Wire	3						
RTC1	RTC Oscillator Input	34						
RTC2	RTC Oscillator Output	33						
PB0.0	Standard I/O	2	VIO	XBR0	✓	✓	INT0.0 WAKE.0	ADC0.20 VREF CMP0P.0
PB0.1	Standard I/O	1	VIO	XBR0	✓	✓	INT0.1 WAKE.2	ADC0.22 CMP0N.0 CMP1P.0 XTAL2

6.4. TQFP-80 Package Specifications

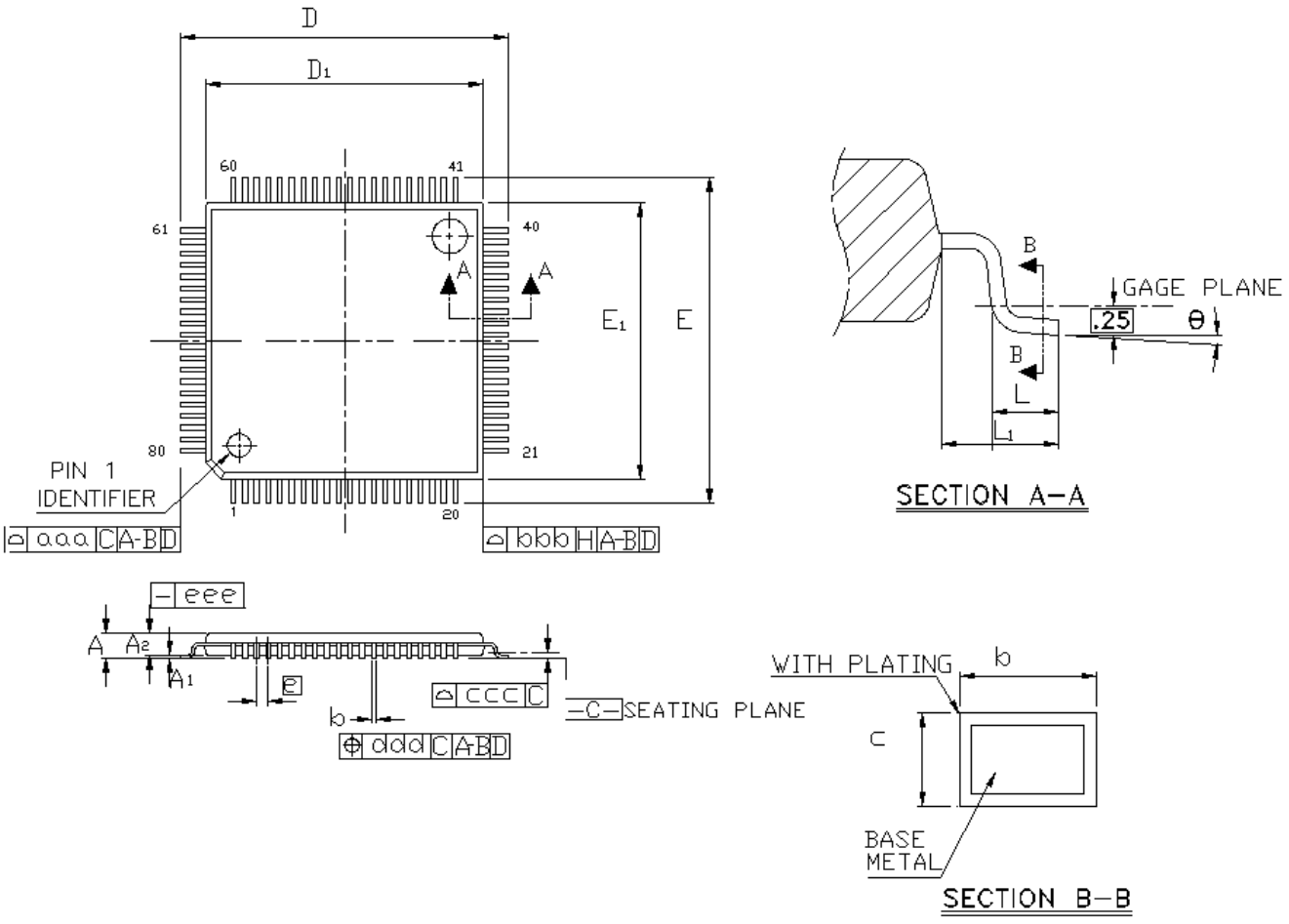

Figure 6.5. TQFP-80 Package Drawing

Table 6.4. TQFP-80 Package Dimensions

Dimension	Min	Nominal	Max
A	—	—	1.20
A1	0.05	—	0.15
A2	0.95	1.00	1.05
b	0.17	0.20	0.27
c	0.09	—	0.20
D	14.00 BSC		
D1	12.00 BSC		
e	0.50 BSC		
E	14.00 BSC		
E1	12.00 BSC		
L	0.45	0.60	0.75
L1	1.00 Ref		
Θ	0°	3.5°	7°
aaa	0.20		
bbb	0.20		
ccc	0.08		
ddd	0.08		
eee	0.05		

Notes:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.
3. This package outline conforms to JEDEC MS-026, variant ADD.
4. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

6.4.1. TQFP-80 Solder Mask Design

All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.

6.4.2. TQFP-80 Stencil Design

1. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
2. The stencil thickness should be 0.125 mm (5 mils).
3. The ratio of stencil aperture to land pad size should be 1:1 for all pads.

6.4.3. TQFP-80 Card Assembly

1. A No-Clean, Type-3 solder paste is recommended.
2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

6.5.1. QFN-64 Solder Mask Design

All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.

6.5.2. QFN-64 Stencil Design

1. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
2. The stencil thickness should be 0.125 mm (5 mils).
3. The ratio of stencil aperture to land pad size should be 1:1 for all pads.
4. A 3x3 array of 1.0 mm square openings on a 1.5 mm pitch should be used for the center ground pad.

6.5.3. QFN-64 Card Assembly

1. A No-Clean, Type-3 solder paste is recommended.
2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

Table 6.8. TQFP-64 Package Dimensions

Dimension	Min	Nominal	Max
A	—	—	1.20
A1	0.05	—	0.15
A2	0.95	1.00	1.05
b	0.17	0.22	0.27
c	0.09	—	0.20
D	12.00 BSC		
D1	10.00 BSC		
e	0.50 BSC		
E	12.00 BSC		
E1	10.00 BSC		
L	0.45	0.60	0.75
Θ	0°	3.5°	7°
aaa	—	—	0.20
bbb	—	—	0.20
ccc	—	—	0.08
ddd	—	—	0.08

Notes:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.
3. This package outline conforms to JEDEC MS-026, variant ACD.
4. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

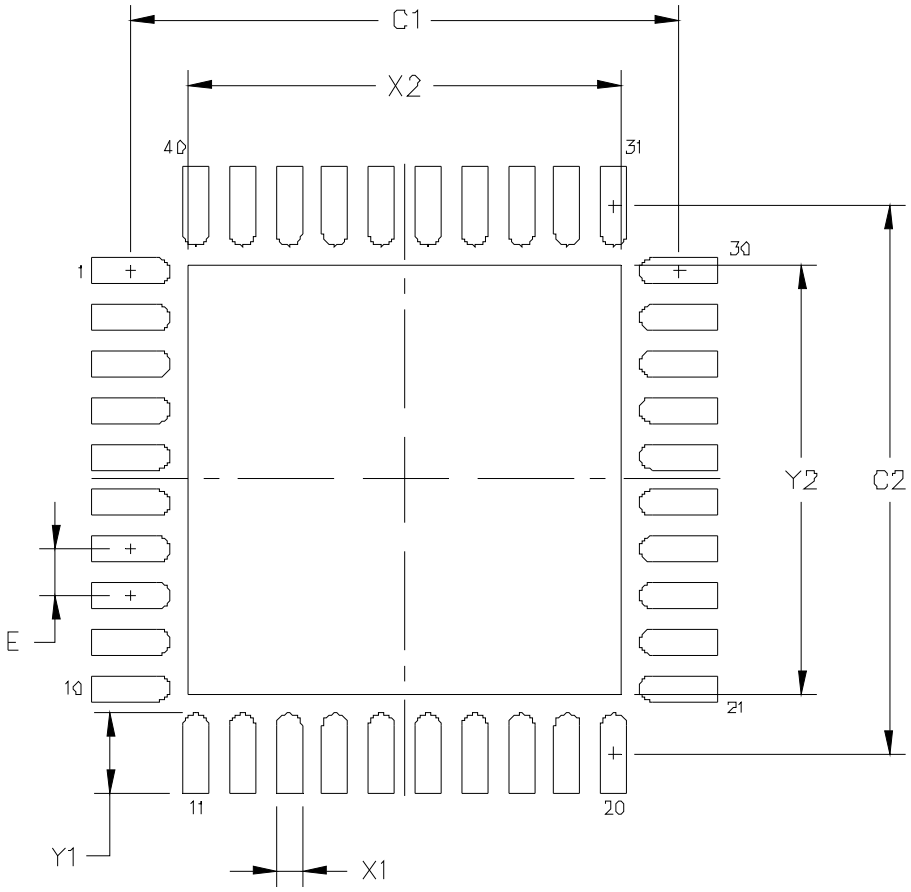

Figure 6.12. QFN-40 Landing Diagram

Table 6.11. QFN-40 Landing Diagram Dimensions

Dimension	mm
C1	5.90
C2	5.90
E	0.50
X1	0.30
Y1	0.85
X2	4.65
Y2	4.65

Notes:
1. All dimensions shown are in millimeters (mm).
2. This Land Pattern Design is based on the IPC-7351 guidelines.
3. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05 mm.